

Notice of References Cited COPY	Application/Control No. 10/282,747	Applicant(s)/Patent Under Reexamination HARARI, ELIYAHOU	
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	R				VIET Q. NGUYEN	
	S				PRIMARY EXAMINER	
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V. Nguyen

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Sheet 1 of 2

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						M-12879 US		10/282,747	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT						Applicant			
(Use several sheets if necessary)						Eliyahou Harari			
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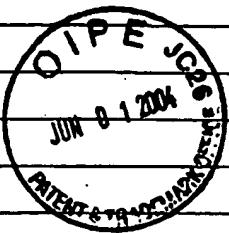
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